U.S. DEPARTMENT OF COMMERCE
PATENT AND TRADEMARK OFFICE

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

ATTY. DOCKET NO.	SERIAL NO.
1-24016	10/722,643
APPLICANT	
Alvin D. Compaan et al.	
FILING DATE	**GROUP**
November 26, 2003	Unassigned

U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
		4,611,091	Sep. 9, 1986	Choudary et al.			
		4,612,411	Sep. 16, 1986	Wieting et al.			
		4,798,660	Jan. 17, 1989	Ermer et al.			
		4,915,745	Apr. 10, 1990	Pollock et al.			
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		5,909,632	Jun. 1, 1999	Gessert			
		6,040,521	Mar. 21, 2000	Kushiya et al.			

FOREIGN PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES	NO

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

		A.N. Tiwari, A. Romeo, D. Baetzner and H. Zogg; Progress in Photovoltaics: Research and Applications; Prog. Photovolt: Res. Appl. 2001; 9:211-215; entitled: "Flexible CdTe Solar Cells on Polymer Films"
		G. Gordillo, M. Grizalez, L.C. Moreno and F. Landazabal; Phys. Stat. Sol. (b) 220, 215 (2000) entitled: "Influence of the Optical Window on the Performance of TCO/CdS/CdTe Solar Cells"
		L. C. Moreno et al.; Phys. Stat. Sol. (b) 220, 289 (2000); entitled: "pH Effect on the Deposition of CdS on ZnO and SnO2:F Substrates by CBD Method"
		Alvin D. Compaan et al.; Annual Technical Report for the Period March, 1998 to March, 1999; Contract No. ZAF-8-17619-14; Dept. of Physics and Astronomy, The University of Toledo; entitled: "High Efficiency Thin Film CdTe and a-Si Based Solar Cells"
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	DATE CONSIDERED 6/19/05